### Ядерное резонансное рассеяние СИ при энергиях выше 30 кэВ. Развитие и применение метода.

Илья Сергеев, PETRAIII, Hamburg, Germany





Линии ядерного резонансного рассеяния:



ID18 @ ESRF





### **Nuclear Resonance Scattering**





### Mössbauer isotopes

H	W - Mössbauer isotopes										He						
Li	Be B C N O F										Ne						
Na	Mg Al Si P S (								Cl	Ar							
K	Ca	Sc	Ti	V	Cr	Mn	Fe	Co	Ni	Cu	Zn	Ga	Ge	As	Se	Br	Kr
Rb	Sr	Y	Zr	Nb	Mo	Tc	Ru	Rh	Pd	Ag	Cd	In	Sn	Sb	Te	Ι	Xe
Cs	Ba	La*	Hf	Ta	W	Re	Os	Ir	Pt	Au	Hg	Tl	Pb	Bi	Po	At	Rn
Fr	Ra	Ac**											•	-	•		

Lanthanides*	Ce	Pr	Nd	Pm	Sm	Eu	Gd	Tb	Dy	Ho	Er	Tm	Yb	Lu
Actinides**	Th	Pa	U	Np	Pu	Am	Cm	Bk	Cf	Es	Fm	Md	No	Lr

Available Mössbauer isotopes: time MS:



NIS:

<sup>57</sup>Fe, <sup>119</sup>Sn, <sup>151</sup>Eu, <sup>149</sup>Sm, <sup>161</sup>Dy, <sup>121</sup>Sb, <sup>125</sup>Te



### **Aplications of time Mössbauer spectroscopy**

#### Collimation of the beam

PRL 109, 026403 (2012) PHYSICAL REVIEW LETTERS

week ending 26 FEBRUARY 2010

Reentrant Valence Transition in EuO at High Pressures: Beyond the Bond-Valence Model N.M. Souza-Neto,<sup>12,4</sup> J. Zhao,<sup>1</sup> E. E. Alp,<sup>1</sup> G. Shen,<sup>3</sup> S. V. Sinogeikin,<sup>3</sup> G. Lapertot,<sup>4</sup> and D. Haskel<sup>1,†</sup>

week ending 13 JULY 2012

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#### High brilliance of the source

PRL 104, 087601 (2010) PHYSICAL REVIEW LETTERS

Nuclear Forward Scattering of Synchrotron Radiation in Pulsed High Magnetic Fields

 measurements under extreme conditions high / low T high pressure magnetic field





### surfaces and nanoscale materials







### **Applications of NIS**

- Geoscience
- glass physics
- nanoscale materials
- thermoelectrics





PRL 100, 235503 (2008)	PHYSICAL	REVIEW	LETTERS	week ending 13 JUNE 2008
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#### Vibrational Properties of Nanograins and Interfaces in Nanocrystalline Materials

S. Stankov,<sup>1</sup> Y.Z. Yue,<sup>2,3</sup> M. Miglierini,<sup>4</sup> B. Sepiol,<sup>5</sup> I. Sergueev,<sup>1</sup> A. I. Chumakov,<sup>1</sup> L. Hu,<sup>2,3</sup> P. Svec,<sup>6</sup> and R. Rüffer<sup>1</sup>





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#### Phonon spectroscopy in a Bi<sub>2</sub>Te<sub>3</sub> nanowire array

Cite this: Nanoscale, 2013, 5, 10629

Dimitrios Bessas,†<sup>ab</sup> William Töllner,<sup>c</sup> Zainul Aabdin,<sup>d</sup> Nicola Peranio,<sup>d</sup> Ilya Sergueev,‡<sup>e</sup> Hans-Christian Wille,<sup>†</sup> Oliver Eibl,<sup>d</sup> Kornelius Nielsch<sup>c</sup> and Raphaël P. Hermann<sup>\*ab</sup>





### Mössbauer Spectroscopy with <sup>61</sup>Ni and <sup>73</sup>Ge

#### <sup>61</sup>Ni:

E = 67.4 keV  $\tau_0$  = 7.60 ns transition: 3/2<sup>-</sup> $\rightarrow$ 5/2<sup>-</sup>

#### Sources:

- <sup>61</sup>Co (β-, 99 min )
- <sup>61</sup>Cu (EC, 3.41 h)

McCammon et al, Hyp. Int. 28 (1986) 483



 $^{73}$ Ge: E = 68.75 keV  $\tau_0$  = 2.51 ns transition: 9/2+→7/2+ <u>Source:</u> Coulomb excitation

Czjzek et al, Physical Review 174 (1968) 331







### **Experimental setup**







Detector: Array of 16 Si APDs Efficiency @ 67keV ~ 20%



### Time MS with <sup>61</sup>Ni and <sup>73</sup>Ge



Time (ns)



R. Simon et al., EPL 104(2013) 17006

Time (ns)

## **Highest pressure for magnetism**

#### X-ray diffraction: fcc phase up to 150 / 200 GPa,

Theory: predicts continuous decrease of magnetic moment up to 300 – 34000 GPa



## **Highest pressure for magnetism**



**Measurements** 

I.Sergueev et al., PRL 111(2013)157601.



H – hyperfine magnetic field

### **Highest pressure for magnetism**



- Ni is ferromagnetic at room temperature up to 260 GPa.
- Measurements at higher pressure are required in order to find critical pressure.

#### Magnetic moment vs volume (theory)



### Hyp. magn. field vs volume (theory)



# **Time MS of Ni at HP. Elastic properties**



### High Resolution Monochromators. Multiple-crystal approach



Si reflections with Bragg angle = 84° Si reflection 17 17 17 777 12 12 12 E, keV 13.9 23.9 33.8  $\Delta E, meV$ 0.7 0.06 5  $\Delta \theta$ , urad 3.4 0.3 0.02 R,% 80 73 22

# SR beam divergence: 10-20 urad

#### 2 steps of collimation:

1. Compound refractive lenses

from 10-20 µrad to 2-5 µrad





### **Backscattering Monochromators**

Burkel, Rep. Prog. Phys. 63(2000)171



Si reflections with Bragg angle = 90°

Si reflection	777	12 12 12	17 17 17
E, keV	13.8	23.7	33.6
$\Delta E, meV$	5	0.7	0.06
$\Delta \theta$ , urad	970	320	83
R,%	80	73	22

Energy is defined by Si crystal lattice

Y.V. Shvyd'ko and E. Gerdau, Hyp. Interact. 123 (1999)

Crystal with low symmetry (sapphire, quartz)



At least 2 reflections in 150-300K for any E > 20keV



### Sapphire backscattering monochromator



### **Experimental Setup and Instrumental Functions**



	101	405-	440 -	100
	<sup>121</sup> Sb	<sup>125</sup> Te	<sup>119</sup> Sn	<sup>129</sup> Xe
E/ keV	37.13	35.49	23.88	39.58
Reflection	(8 16 40)	(9 1 68)	(4 4 45)	(5 17 54)
Т/К	237	220	193	291
Angle / degree	59	24	26	49
				-1
$\Delta \mathbf{E}_{th}$ / meV	0.4	0.7	1.0	0.5
$\Delta \mathbf{E}_{\mathbf{exp}}$ / meV	0.7	0.7	1.0	0.9

Energy band width ~0.7 meV,

 $\Delta E / E = 2 \cdot 10^{-8}$ 



### **Application. Phonons in Sb<sub>2</sub>Te<sub>3</sub>**





### **Thermoelectrics.Current trends**



#### **Commercial materials**

Snyder and Toberer, Nature Mat. 7(2008)

### Search for "phonon glass, electron crystal"



TEM images of a  $Si_{80}Ge_{20}$  nanocomposite Wang et al., Appl. Phys. Lett., 93 (2008).



### **Thermoelectrics. Skutterudites**



Lattice thermal conductivity



Sales et al., Science, 272(1996)

Is CoSb<sub>3</sub> a good reference for filled skutterudite lattice dynamics?

FeSb<sub>3</sub> is thermodynamically unstable.



Synthesis of Metastable FeSb<sub>3</sub> using multilayer precursors (Hornbostel et al., J. Am. Chem. Soc. 1997, 119, 2665)

#### $\rightarrow$ 1-1.5 µm films of **FeSb**<sub>3</sub>



Möchel et al, Phys. Rev. B, 84(2011)064302



### Phonons in skutterudites. EuFe<sub>4</sub>Sb<sub>12</sub> vs FeSb<sub>3</sub>





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### Phonons in skutterudites. High pressure study



Grüneisen parameter



### **High pressure diffraction**





### **Sapphire monochromator. Perspectives**

#### Improvement of the sapphire quality

at 35 k	keV	а	t 50 keV
thickness	∆E / meV	thickne	ss Refl-ty / %
1 mm	0.7	1 mm	2
2 mm	0.3	2 mm	7
5 mm	0.1	5 mm	30

#### Resolution to measure:

- phonon line broadening
- mean sound velocity

New elements: <sup>183</sup>W 46.5 keV <sup>189</sup>Os 36.2 keV <sup>238</sup>U 44.9 keV <sup>240</sup>Pu 42.8 keV

#### Sapphire ultraoptics for synchrotron radiation

Helmholtz-Russia Joint Research Group HRJRG-402 Partners: Russia - RAS Shubnikov IC, Moscow Germany – Forschungszentrum Jülich, DESY, ANKA

### Apply for extreme conditions (high P):

#### Feasibility high pressure study: R.Simon et al., Semicond. Sci. Technol. 00 (2014)



Requires setup to perform low T/ high pressure measurements



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P01

**Bayerisches Geoinstitut** Leonid Dubrovinsky



# внимание

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MANNIN

YHNBEPCHTET



### **Quality of sapphire crystals**









### Time Mössbauer spectroscopy above 60 keV



### Phase change materials for storage devices



### Candidate for memory materials:

- Fast ~10 ns
- Dense ∅ << 50nm</li>
- Stable several years /bit
- Long-lived 10<sup>12</sup> cycles

Today: optical contrast: storage media, DVD, Blu-Ray. Future: resistivity contrast: fast non volatile memory!



### Elastic properties of Ge<sub>2</sub>Sb<sub>2</sub>Te<sub>4</sub>

### Hardening upon crystallization



	Amorphous	Crystalline
<b>C</b> <sub>11</sub>	31 GPa	48 GPa
VL	2280 m/s	2770 m/s
<b>C</b> <sub>44</sub>	10 GPa	16 GPa
V <sub>T</sub>	1300 m/s	1600 m/s
V <sub>Debye</sub>	1440 m/s	1770 m/s

Blachowicz et al., J. Appl. Phys. **102**, 093519 (2007)

#### Softening upon crystallization



Matsunaga et al., Adv. Funct. Mater. 21(2011)2232



### Amorphous and crystalline state of Ge<sub>2</sub>Sb<sub>2</sub>Te<sub>4</sub>

Sample: ~1 µm film deposited on AI, T=20 K

Matsunaga et al., Adv. Funct. Mat., 21(2011)2232



	SI	С	Те			
	B, Å <sup>2</sup>	F, N/m	B, Å <sup>2</sup>	F, N/m		
Amorphous	0.184(2)	97(4)	0.198(2)	84(4)		
NaCl	0.166(2)	72(4)	0.160(2)	68(4)		





Crystalline: Weak "resonance" bonding

Combination of NIS on <sup>125</sup>Te and <sup>121</sup>Sb and INS (IXS)  $\Rightarrow$  Ge PDOS



### **Thermoelectrics. Applications**

ТГ-1, «партизанский котелок» Юрий Маслаковец, Лениградский физтех, 1943





Radioisotope Thermoelectric Generator, Mars Science Laboratory https://solarsystem.nasa.gov/rps/rtg.cfm



Thermoelectric stations for gas pipe lines http://www.telgen.ru/









http://biolitestove.com/products/campstove/

